# **SEMICONDUCTOR**

TECHNICAL DATA

## BC337/338

# BC337/BC338 TRANSISTOR (NPN)

#### **FEATURES**

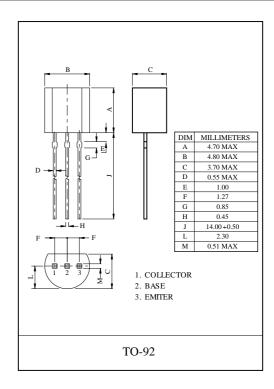
· High Current : I<sub>C</sub>=800mA.

· DC Current Gain :  $h_{FE}=100\sim630$  ( $V_{CE}=1V,\ I_c=100mA$ ).

· For Complementary with PNP type BC327.

### MAXIMUM RATINGS (Ta=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit		
V <sub>CBO</sub>	Collector-Base Voltage	BC337	50	V	
		BC338	30	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	BC337	45	V	
		BC338	25	V	
V <sub>EBO</sub>	Emitter-Base Voltage		5	V	
Ic	Collector Current -Continuous		800	mA	
P <sub>D</sub>	Total Device Dissipation		625	mW	
Tj	Junction Temperature		150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature		-55-150	$^{\circ}$	



### ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter		Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage		V <sub>CBO</sub>	I <sub>C</sub> = 100uA, I <sub>E</sub> =0				
	BC337			50			V
	BC338			30			V
Collector-emitter breakdown voltage			I <sub>C</sub> = 10mA , I <sub>B</sub> =0				
	BC337	$V_{\sf CEO}$		45			V
	BC338			25			V
Emitter-base breakdown voltage		$V_{EBO}$	I <sub>E</sub> = 10uA, I <sub>C</sub> =0	5			V
Collector cut-off current	BC337	I <sub>CBO</sub>	V <sub>CB</sub> = 45V, I <sub>E</sub> =0			0.1	^
	BC338		$V_{CB}$ = 25V, $I_E$ =0			0.1	uA
Collector cut-off current	BC337		$V_{CE}$ = 40V, $I_{B}$ =0			0.2	uA
	BC338	I <sub>CEO</sub>	$V_{CE}$ = 20V, $I_{B}$ =0			0.2	uA
Emitter cut-off current		$I_{EBO}$	$V_{EB}=4 V, I_{C}=0$			0.1	uA
BC337/BC338 BC337-16/BC338-16 BC337-25/BC338-25				100		630	
		h <sub>FE(1)</sub>	V <sub>CE</sub> =1V, I <sub>C</sub> = 100mA	100		250	
				160		400	
BC337-40	)/BC338-40			250		630	
DC current gain		$h_{FE(2)}$	$V_{CE}=1V$ , $I_{C}=300mA$	60			
Collector-emitter saturation voltage		V <sub>CE(sat)</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> = 50mA			0.7	V
Base-emitter saturation voltage		V <sub>BE(sat)</sub>	I <sub>C</sub> = 500mA, I <sub>B</sub> =50mA			1.2	V
Base-emitter voltage		V <sub>BE</sub>	V <sub>CE</sub> =1V, I <sub>C</sub> = 300mA			1.2	V
Transition frequency		f <sub>T</sub>	$V_{CE}$ = 5V, $I_{C}$ = 10mA $f$ = 100MHz	210			MHz
Collector Output Capacitance		Cob	V <sub>CB</sub> =10V,I <sub>E</sub> =0 f=1MHZ		15		pF